



DGD21064M

HIGH-SIDE AND LOW-SIDE GATE DRIVER IN SO-14 (Type TH)

Description

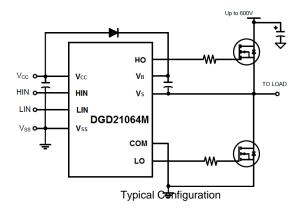
The DGD21064M is a high-voltage / high-speed gate driver capable of driving N-Channel MOSFETs and IGBTs in a half bridge configuration. High-voltage processing techniques enable the DGD21064M's high-side to switch to 600V in a bootstrap operation.

The DGD21064M logic inputs are compatible with standard TTL and CMOS levels (down to 3.3V) to interface easily with controlling devices. The driver outputs feature high pulse current buffers designed for minimum driver cross conduction.

The DGD21064M is available in a 14-pin SO-14 (Type TH) package and operates over an extended -40°C to +125°C temperature range.

Applications

- DC-DC Converters
- DC-AC Inverters
- AC-DC Power Supplies
- Motor Controls
- Class D Power Amplifiers



Features

- Floating High-Side Driver in Bootstrap Operation to 600V
- Drives Two N-Channel MOSFETs or IGBTs in Half Bridge Configuation
- Outputs Tolerant to Negative Transients
- Wide Logic and Low-Side Gate Driver Supply Voltage: 10V to 20V
- Wide Logic Supply Voltage Offset Voltage: -5V to 5V
- Logic Input (HIN and LIN) 3.3V Capability
- Schmitt Triggered Logic Inputs with Internal Pull Down
- Undervoltage Lockout for High and Low Side Drivers
- Extended Temperature Range: -40°C to +125°C
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: SO-14 (Type TH)
- Case Material: Molded Plastic. "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 63
- Weight: 0.142 grams (Approximate)



SO-14 (Type TH) Top View

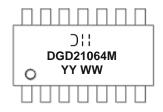
Ordering Information (Note 4)

Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
DGD21064MS14-13	DGD21064M	13	16	2,500

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

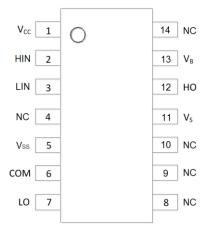
Marking Information



⊃¦¦ = Manufacturer's Marking DGD21064M = Product Type Marking Code YY = Year (ex: 17 = 2017) WW = Week (01 to 53)



Pin Diagrams

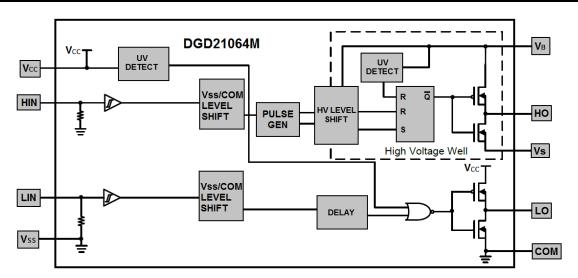


Top View: SO-14 (Type TH)

Pin Descriptions

Pin Number	Pin Name	Function
1	Vcc	Low-side and logic fixed supply
2	HIN	Logic input for high-side gate driver output, in phase with HO (Referenced to V _{SS})
3	LIN	Logic input for low-side gate driver output, in phase with LO (Referenced to V _{SS})
4, 8, 9, 10, 14	NC	No connection (No Internal Connection)
5	V_{SS}	Logic ground
6	COM	Low-side return
7	LO	Low-side gate drive output
11	Vs	High-side floating supply return
12	НО	High-side gate drive output
13	V_{B}	High-side floating supply

Functional Block Diagram





Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
High-side Floating Supply Voltage	V _B	-0.3 to +624	V
High-side Floating Supply Offset Voltage	Vs	V _B -24 to V _B +0.3	V
High-side Floating Output Voltage	V _{HO}	V _S -0.3 to V _B +0.3	V
Offset Supply Voltage Transient	dV _S / dt	50	V/ns
Low-side and Logic Fixed Supply Voltage	V _{CC}	-0.3 to +24	V
Low-side Output Voltage	V_{LO}	-0.3 to V _{CC} +0.3	V
Logic Supply Offset Voltage	V _{SS}	V _{SS} -24 to V _{CC} +0.3	V
Logic Input Voltage (HIN and LIN)	V _{IN}	V _{SS} -0.3 to V _{CC} +0.3	V

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation Linear Derating Factor (Note 5)	P _D	1.0	W
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	120	°C/W
Operating Temperature	TJ	+150	
Lead Temperature (Soldering, 10s)	TL	+300	°C
Storage Temperature Range	T _{STG}	-55 to +150	

Note: 5. When mounted on a standard JEDEC 2-layer FR-4 board.

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
High-side Floating Supply Absolute Voltage	V _B	V _S + 10	V _S + 20	V
High-side Floating Supply Offset Voltage	Vs	(Note 6)	600	V
High-side Floating Output Voltage	V _{HO}	Vs	V _B	V
Low-side Fixed Supply Voltage	Vcc	10	20	V
Low-side Output Voltage	V_{LO}	COM	V _{CC}	V
Logic Input Voltage (HIN and LIN)	V _{IN}	V _{SS}	5	V
Logic Ground	V _{SS}	-5	5	V
Ambient Temperature	T _A	-40	+125	°C

Note: 6. Logic operation for V_S of -5V to +600V. Logic state held for V_S of -5V to -V_{BS}.



$\textbf{DC Electrical Characteristics} \ (V_{\text{BIAS}} \ (V_{\text{CC}}, \ V_{\text{BS}}) = 15 \text{V}, \ V_{\text{SS}} = \text{COM}, \ @T_{\text{A}} = +25 ^{\circ}\text{C}, \ \text{unless otherwise specified.}) \ (\text{Note 7})$

Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Logic "1" Input Voltage	V _{IH}	2.5	_	_	V	V _{CC} = 10V to 20V
Logic "0" Input Voltage	V _{IL}	_	_	0.6	V	V _{CC} = 10V to 20V
High Level Output Voltage, V _{BIAS} - V _O	VoH	_	0.05	0.2	V	$I_O = 2mA$
Low Level Output Voltage, VO	V_{OL}	_	0.02	0.1	V	$I_O = 2mA$
Offset Supply Leakage Current	I _{LK}	_	_	50	μΑ	$V_B = V_S = 600V$
Quiescent V _{BS} Supply Current	I_{BSQ}	20	75	130	μΑ	V _{IN} = 0V or 5V
Quiescent V _{CC} Supply Current	Icca	60	120	180	μΑ	V _{IN} = 0V or 5V
Logic "1" Input Bias Current	I _{IN+}	_	5.0	20	μΑ	V _{IN} = 5V
Logic "0" Input Bias Current	I _{IN-}	_	_	5.0	μΑ	$V_{IN} = 0V$
V _{BS} Supply Undervoltage Positive Going Threshold	V_{BSUV+}	8.0	8.9	9.8	V	_
V _{BS} Supply Undervoltage Negative Going Threshold	V _{BSUV} -	7.4	8.2	9.0	V	_
V _{CC} Supply Undervoltage Positive Going Threshold	V _{CCUV+}	8.0	8.9	9.8	V	_
V _{CC} Supply Undervoltage Negative Going Threshold	V _{CCUV} -	7.4	8.2	9.0	V	_
Lhyotoriaia	V _{CCUVH}	0.3	0.7	_	V	_
Hysterisis	V_{BSUVH}	0.3	0.7	_	V	_
Output High Short Circuit Pulsed Current	I _{O+}	130	290	_	mA	V _O = 0V, PW ≤ 10μs
Output Low Short Circuit Pulsed Current	I _{O-}	270	600	_	mA	V _O = 15V, PW ≤ 10μs

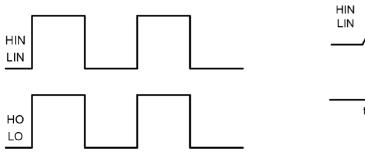
Note: 7. The V_{IN} and I_{IN} parameters are referenced to COM and are applicable to the two logic pins: HIN and LIN. The V_O and I_O parameters are referenced to COM and are applicable to the respective output pins: HO and LO.

AC Electrical Characteristics (V_{BIAS} (V_{CC}, V_{BS}) = 15V, C_L = 1000pF, V_{SS} = COM, @T_A = +25°C, unless otherwise specified.)

Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Turn-on Propagation Delay	toN	_	220	300	ns	$V_S = 0V$
Turn-off Propagation Delay	toff	_	200	280	ns	V _S = 0V or 600V
Delay Matching	t _{DM}	_	_	30	ns	_
Turn-on Rise Time	t _R	_	100	220	ns	$V_S = 0V$
Turn-off Fall Time	t _F	_	35	80	ns	$V_S = 0V$



Timing Waveforms



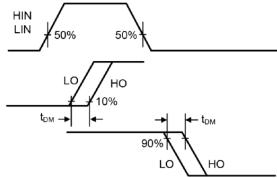


Figure 1. Input / Output Timing Diagram

Figure 2. Delay Matching Waveform Definitions

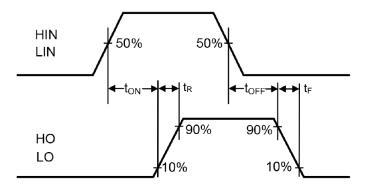


Figure 3. Switching Time Waveform Definitions



Typical Performance Characteristics (@T_A = +25°C, unless otherwise specified.)

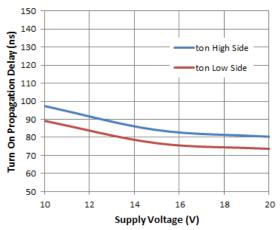


Figure 4. Turn-on Propagation Delay vs. Supply Voltage

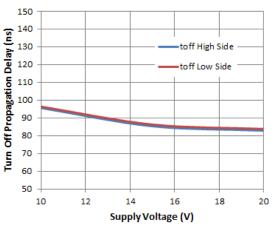


Figure 6. Turn-off Propagation Delay vs. Supply Voltage

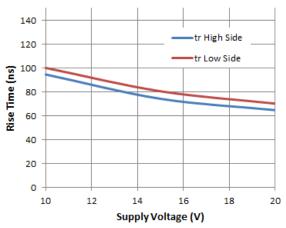


Figure 8. Rise Time vs. Supply Voltage

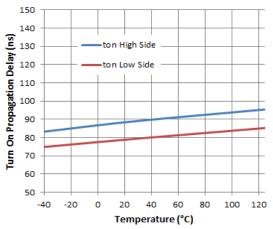


Figure 5. Turn-on Propagation Delay vs. Temperature

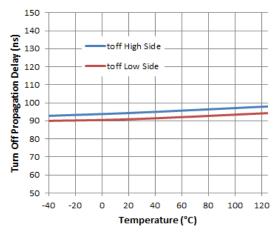


Figure 7. Turn-off Propagation Delay vs. Temperature

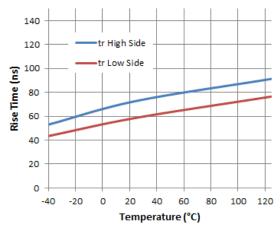


Figure 9. Rise Time vs. Temperature



Typical Performance Characteristics (continued)

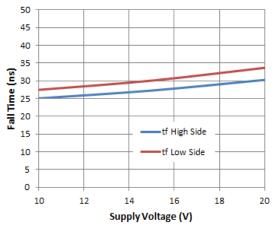
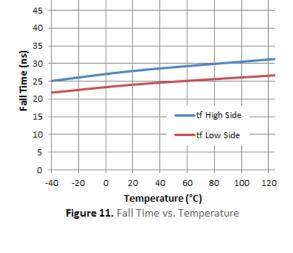


Figure 10. Fall Time vs. Supply Voltage



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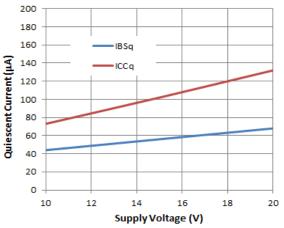


Figure 12. Quiescent Current vs. Supply Voltage

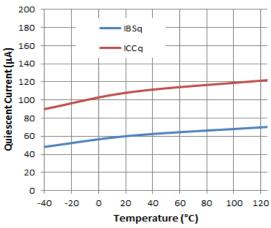


Figure 13. Quiescent Current vs. Temperature

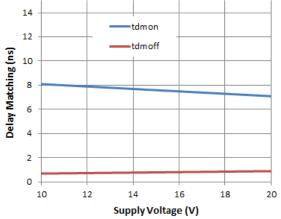


Figure 14. Delay Matching vs. Supply Voltage

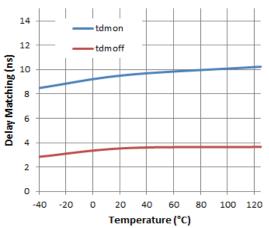


Figure 15. Delay Matching vs. Temperature



Typical Performance Characteristics (cont.)

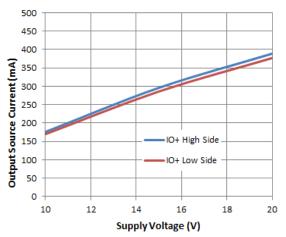


Figure 16. Output Source Current vs. Supply Voltage

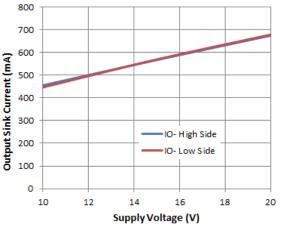


Figure 18. Output Sink Current vs. Supply Voltage

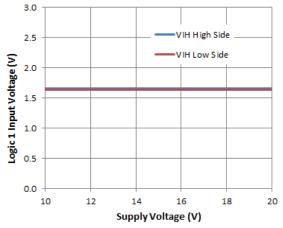


Figure 20. Logic 1 Input Voltage vs. Supply Voltage

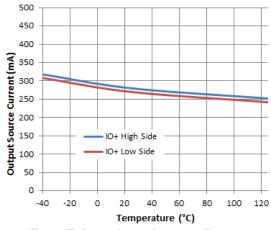


Figure 17. Output Source Current vs. Temperature

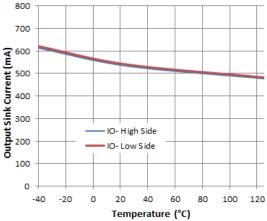


Figure 19. Output Sink Current vs. Temperature

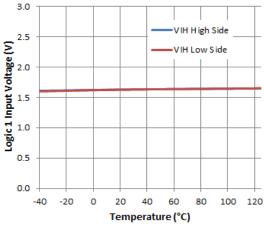


Figure 21. Logic 1 Input Voltage vs. Temperature



Typical Performance Characteristics (cont.)

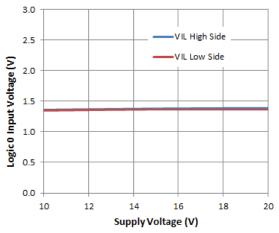


Figure 22. Logic O Input Voltage vs. Supply Voltage

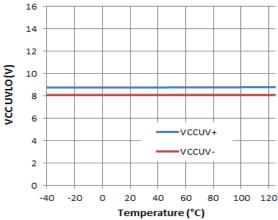


Figure 24. VCC UVLO vs. Temperature

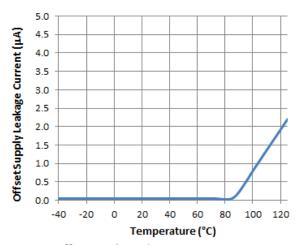


Figure 26. Offset Supply Leakage Current vs. Temperature

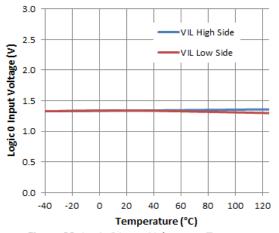


Figure 23. Logic 0 Input Voltage vs. Temperature

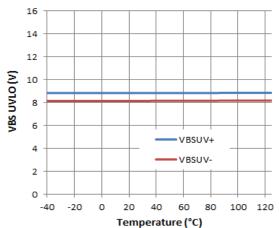


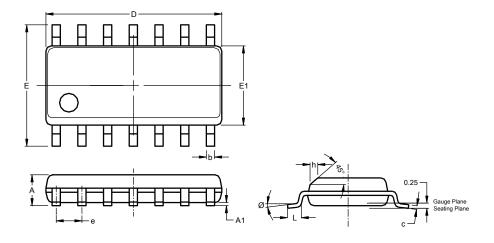
Figure 25. VBS UVLO vs. Temperature



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-14 (Type TH)

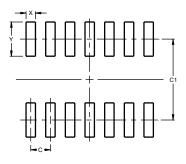


SO-14 (Type TH)					
Dim					
Α	1.55	1.73			
A1	0.10	0.25			
b	0.35	0.51			
С	0.190	0.248			
D	8.56	8.74	8.61		
Е	5.84	6.20	6.00		
E1	3.81	3.99	3.94		
е			1.27		
h			0.33		
٦	0.41	0.89			
Ø	0°	8°			
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-14 (Type TH)



Dimensions	Value (in mm)
С	1.27
C1	5.20
Х	0.60
Υ	2.20

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.



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